IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Kousuke SUZUKE, et al.

Serial Number: 09/045,118

Filed: March 20, 1998

For: SEMICONDUCTOR DEVICE HAVING AN INSULATION FILM WITH REDUCED WATER CONTENT (AS AMENDED)

AMENDMENT

Director of Patents and Trademarks
Washington, D.C. 20231

October 12, 2000

Sir:

In response to the Office Action dated August 15, 2000, extended to October 15, 2000 by a one month Petition for Extension of Time, please amend the above-identified application as follows:

IN THE CLAIMS:

Claim 33, as previously amended, is reproduced here for reference.

33. (Amended) A semiconductor device as claimed in claim 28, further comprising another silicide region formed selectively on a surface of said gate electrode.